Document Number: SMAV3640-100 Preliminary Datasheet V1.0

3.6-4GHz, 100W, 50V GaN matched PA Module

Description

The SMAV3640-100 is a 100-watt, integrated 2-stage Power Amplifier Module, designed for 5G massive MIMO applications, with frequencies from 3.6 to 4GHz. The module is 50 Ω input fully matched and output partially matched, and requires minimal external components. The module offers a much smaller footprint than traditional discrete component solutions, with much less sensitivity for production, housed in 10*6mm cost effective plastic open cavity package, and heat dissipated by copper flange.



The module incorporates advanced Doherty circuit delivering high power added efficiency for the entire module at 16W average power according to normal 8 dB back off.

Innogration owns the patents for internal Doherty architecture, and related plastic open cavity.

• Typical Performance of Doherty Demo (On Innogration fixture with device soldered with grounding vias): VDS= 50V, IDQ-main=58mA Vgs-main=-2.96V. Vgs-peak=-5.3V, Idq-driver=21mA, Vgs-Driver=-3.05V

Freq(MHz)	Pout(dBm)	CCDF(dB	Ppeak(dBm)	Ppeak(W)	ACPR(dBc)	Gain(dB)	Efficiency(%)
3600	41.96	8.38	50.34	108.06	-30.72	28.85	45.32
3800	41.97	8.94	50.91	123.33	-35.52	29.57	45.44
4000	41.98	8.42	50.41	109.78	-32.66	28.90	45.31

Notes:

- Pulse Width=20 us, Duty cycle=10% WCDMA signal: 3GPP test model 1; 1 to 64 DPCH; Channel Bandwidth=3.84MHz,PAR =10.5 dB at 0.01 % probability on CCDF.

Features and Benefits

- · Adjustable drain bias to fit different power demand
- Extremely good VBW performance to enable the broadest IBW/OBW
- · Industry leading RF performance for 5G MIMO AAU, for instance
- 32T:320W to 400W / 200MHz
- · Plastic open cavity without molding compound brings advantage compared to molded design
- Minimize the risk of high density thermal distribution in fanless system for longer life time
- Highly consistent RF performance for yield of volume production
- 50 Ω Input matched, output partially matched, effective PCB space smaller than 12*20mm
- Integrated Doherty Final and driver Stage
- 6x10 mm Surface Mount Package, full copper flange underneath for grounding and heat dissipation, much more effective than LGA PCB based design

Pin Configuration and Description





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Pin No.	Symbol	Description		
6	RF IN	RF Input		
1 VDS-driver		Driver stage, Drain Bias		
4	VGS-driver Driver stage, Gate Bias			
19,21	RF Out2	RF Output,Main Amplifier		
22,24 RF Ou		RF Output, Peaking Amplifier		
11 VGS-m		Main Amplifier, Gate Bias		
16,17	VDS-main	Main Amplifier, Drain Bias		
32 VGS-peak		Peaking Amplifier, Gate Bias		
26,27	VDS-Peak	Peaking Amplifier, Drain Bias		
3,8-10,14,15,28,29,33-35	NC	No connection		
2,5,7,12,13,18,20,23,25,30,31,36	GND	Internal Grounding, recommend connecting to Epad ground		
Package Base GND		DC/RF Ground. Must be soldered to EVB ground plane over array of vias for thermal and RF performance. Solder voids under Pkg Base will result in excessive junction temperatures causing permanent damage.		

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DrainSource Voltage	V _{DSS}	200	Vdc
GateSource Voltage	V _{GS}	-8 to +0.6	Vdc
Operating Voltage	V _{DD}	+60	Vdc
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	Tc	+150	°C
Operating Junction Temperature	T₃	+225	°C

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance@Average Power, Junction to Case	Rejc	2.9	°C/W
Tcase=+85℃, CW Test, , Pout=16W,	KejC	2.9	-0/00

Notes:

- (1) The thermal resistance is acquired by our company's FEA model, which was calibrated by IR measurement, the value shall be applied to reliability.
- (2) The reference Tcase temperature 85℃ is apply on the backside of package.
- (3) If the device soldering onto the 20mil Rogers PCB with 108 × Φ 0.25mm via hole beneath the package backside and the reference temperature Tcase (85°C) apply on the groundside of the PCB, the total thermal resistance R θ JC (TBD)°C/W.
- (4) The power dissipation in the table is overall dissipation which includes Carrier PA, Peaking PA and driver PA..

Table 3. ESD Protection Characteristics

Test Methodology	Class Voltage
Human Body Model(HBM) (JEDEC Standard JESD-A114)	TBD
Charged Device Model (CDM) (JEDEC Standard JESD22-C101F)	±1000V

Table 4. Electrical Characteristics

Parameter	Condition	Min	Тур	Max	Unit
Frequency Range		3.6		4.0	GHz
Driver Quiescent Current (I _{DQ-driver)}			20		mA
Carrier Quiescent Current (I _{DQ-main})			55		mA
Peak PA Gate Quiescent Voltage (VPEAK)			-5.0		V
Power Gain @ Pout=40.5dBm	Freq=3.6GHz	28	29		dB

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Efficiency @Pout=40.5dBm	Freq=3.6GHz	44	46	%
Ppeak by CCDF	Freq=3.6GHz		110	W

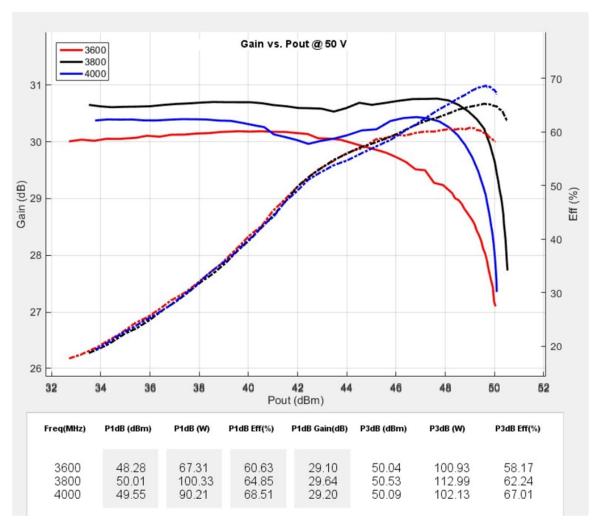
Load Mismatch of per Section (On Test Fixture, 50 ohm system): f = 3.6GHz

VSWR 10:1 at P3dB pulse CW Output Power	No Device Degradation
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TYPICAL CHARACTERISTICS

Application board and its layout info based on request

Figure 1. Power Gain and Drain Efficiency as Function of Pulsed CW Output Power





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Figure 2. Network analyzer output S11/S21

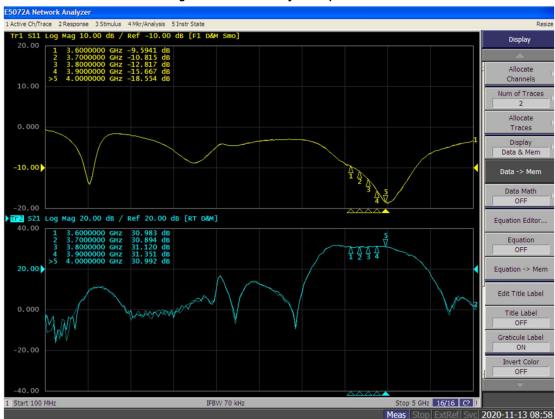
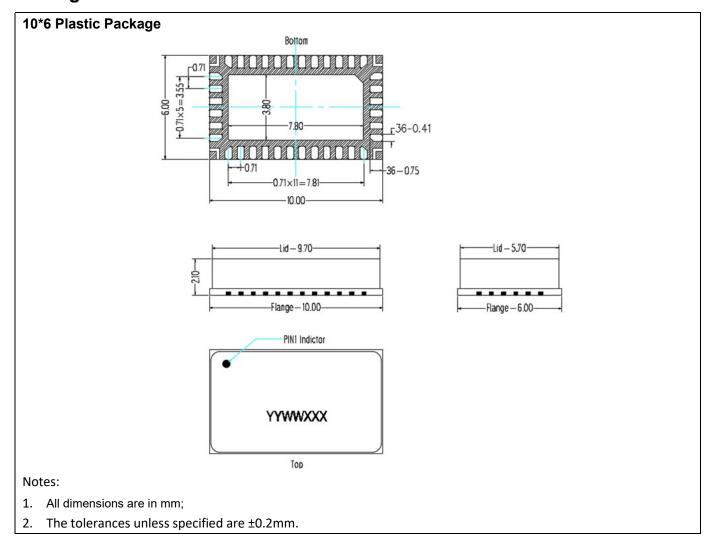


Figure 3. Video Impedance Test

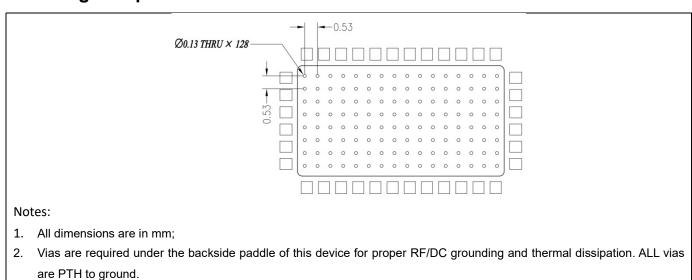


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Package Dimensions



Mounting Footprint Pattern



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Revision history

Table 5. Document revision history

Date	Revision	Datasheet Status
2020/11/13	Rev 1.0	Preliminary Datasheet

Application data based on LWH-20-36

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